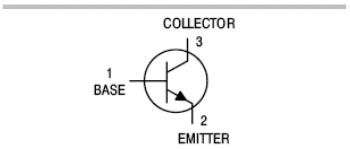
NPN Small Signal Surface Mount Transistor

BC846-BC848

Features

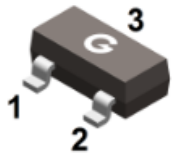
HF

- High current gain
- Excellent h_{FE} linearity
- Low noise between 30Hz and 15kHz



Mechanical Data

- Case: SOT-23
- Molding compound: UL flammability classification rating 94V-0
- Terminals: Tin-plated; solderability per MIL-STD-202, Method 208



SOT-23

Ordering Information

Part Number	Package	Shipping Quantity	Marking Code
BC846A/B	SOT-23	3000 pcs / Tape & Reel	1A/1B
BC847A/B/C	SOT-23	3000 pcs / Tape & Reel	1E/1F/1G
BC848A/B/C	SOT-23	3000 pcs / Tape & Reel	1J/1K/1L

Maximum Ratings (@ T_A = 25℃ unless otherwise specified)

Parameter	Symbol	BC846	BC847	BC848	Unit
Collector-Base Voltage	V_{CBO}	80	50	30	V
Collector-Emitter Voltage	V_{CEO}	65	45	30	V
Emitter-Base Voltage	V_{EBO}	6	6	5	V
Collector Current (Continuous)	I_C	100			mA
Collector Current (Peak)	I_{CM}	200			mA

Thermal Characteristics

Parameter	Symbol	Value	Unit
Power Dissipation (T_A = 25°C)	P_D	250	mW
Thermal Resistance Junction-to-Air *1	$R_{\theta JA}$	409	°C/W
Thermal Resistance Junction-to-Case *1	$R_{\theta JC}$	225	°C/W
Thermal Resistance Junction-to-Lead *1	$R_{\theta JL}$	197	°C/W
Operating Junction Temperature	T_J	-55 ~ +150	°C
Storage Temperature Range	T_{STG}	-55 ~ +150	°C

Note 1: The data tested by surface mounted on a 15mm * 15mm * 1mm FR4-epoxy P.C.B

Electrical Characteristics (@ T_A = 25℃ unless otherwise specified)

Parameter	Symbol	Test Condition	Min.	Typ.	Max.	Unit
Collector-Base Breakdown Voltage BC846	$V_{(BR)CBO}$	I_C = 10μA, I_E = 0	80	-	-	V
Collector-Base Breakdown Voltage BC847			50	-	-	
Collector-Base Breakdown Voltage BC848			30	-	-	
Collector-Emitter Breakdown Voltage BC846	$V_{(BR)CEO}$	I_C = 10mA, I_B = 0	65	-	-	V
Collector-Emitter Breakdown Voltage BC847			45	-	-	V
Collector-Emitter Breakdown Voltage BC848			30	-	-	V
Emitter-Base Breakdown Voltage BC846	$V_{(BR)EBO}$	I_E = 10μA, I_C = 0	6	-	-	V
Emitter-Base Breakdown Voltage BC847			6	-	-	V
Emitter-Base Breakdown Voltage BC848			5	-	-	V
Collector Cut-off Current	I_{CBO}	V_{CB} = 30V, I_E = 0	-	-	15	nA
		V_{CB} = 30V, I_E = 0 T_J = 150°C	-	-	5	μA
Emitter-base Cut-off Current	I_{EBO}	V_{EB} = 5V, I_C = 0	-	-	100	nA
Collector-emitter Cut-off Current	I_{CEO}	V_{CE}= 30V, I_B = 0	-	-	1	mA
DC Current Gain BC846/847/848A	h_{FE}	V_{CE} = 5V, I_C = 10μA	-	110	-	-
DC Current Gain BC846/847/848B			-	250	-	-
DC Current Gain BC847/848C			-	480	-	-
DC Current Gain BC846/847/848A		V_{CE} = 5V, I_C = 2mA	110	-	220	-
DC Current Gain BC846/847/848B			200	-	450	-
DC Current Gain BC847/848C			420	-	800	-
Collector-Emitter Saturation Voltage	$V_{CE(sat)}$	I_C = 10mA, I_B = 0.5mA	-	0.09	0.25	V
		I_C = 100mA, I_B = 5mA	-	0.20	0.60	V
Base-Emitter Saturation Voltage	$V_{BE(sat)}$	I_C = 10mA, I_B = 0.5mA	-	0.70	0.90	V
		I_C = 100mA, I_B = 5mA	-	0.90	1.10	V
Base-Emitter Voltage	$V_{BE(ON)}$	V_{CE} = 5V, I_C= 2mA	0.58	0.66	0.70	V
		V_{CE} = 5V, I_C= 10mA	-	-	0.77	V
Transition Frequency	f_T	V_{CE} = 5V, I_C= 10mA f = 100MHz	100	-	-	MHz
Collector Capacitance	C_C	V_{CB} = 10V, I_E = I_e = 0 f = 100MHz	-	2.5	-	pF

Ratings and Characteristic Curves-BC846/847/848A (@ T_A = 25℃ unless otherwise specified)

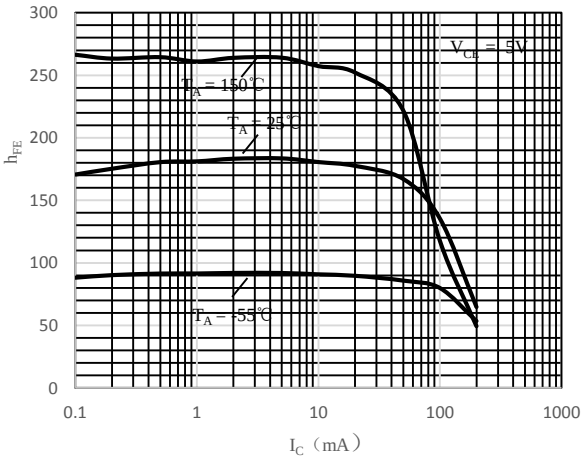


Fig 1 h_{FE} vs. I_C

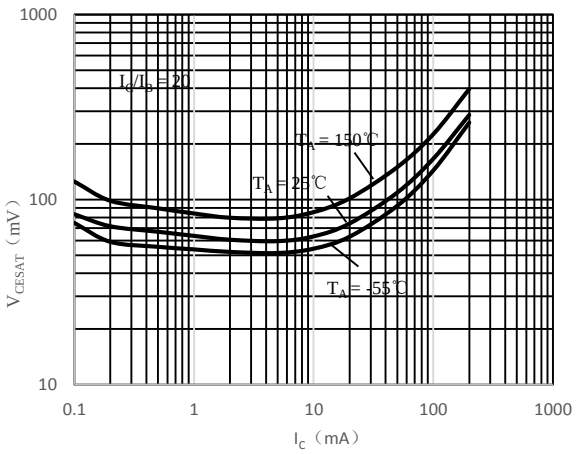


Fig 2 $V_{CE(sat)}$ vs. I_C

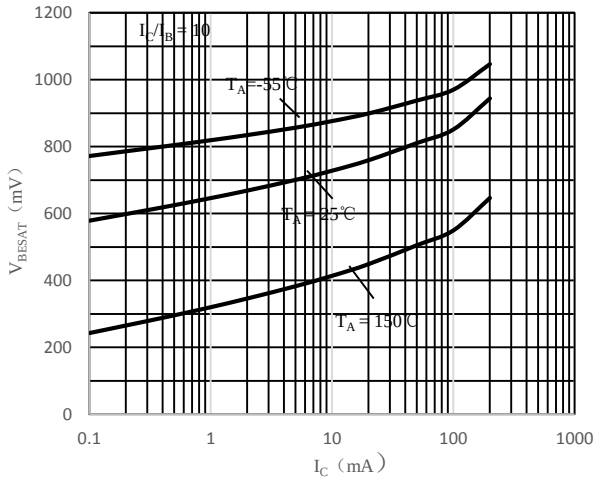


Fig 3 $V_{BE(sat)}$ vs. I_C

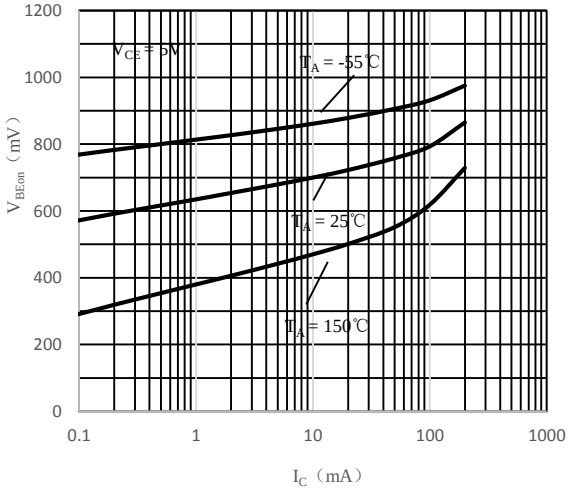


Fig 4 $V_{BE(ON)}$ vs. I_C

Ratings and Characteristic Curves-BC846/847/848B (@ T_A = 25℃ unless otherwise specified)

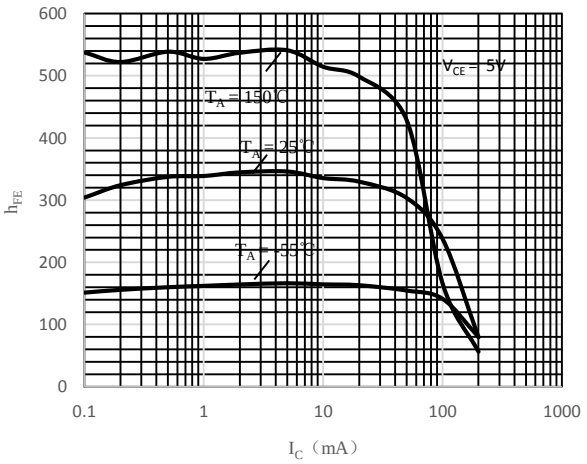


Fig 1 h_{FE} vs. I_C

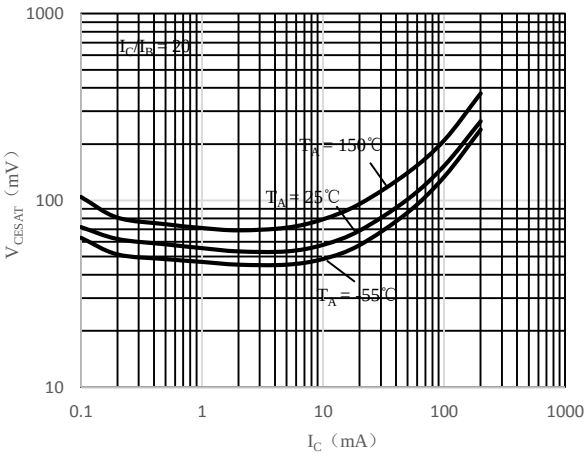


Fig 2 $V_{CE(sat)}$ vs. I_C

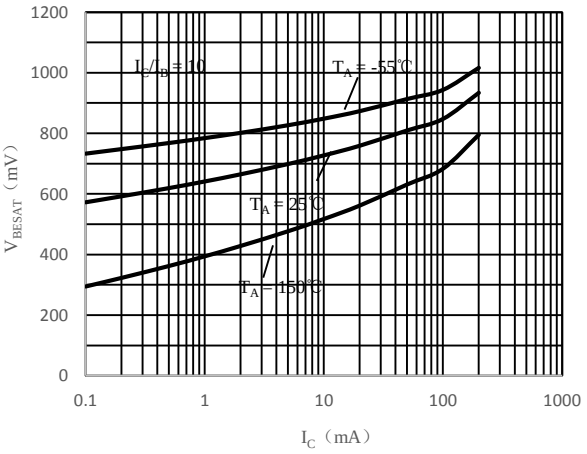


Fig 3 $V_{BE(sat)}$ vs. I_C

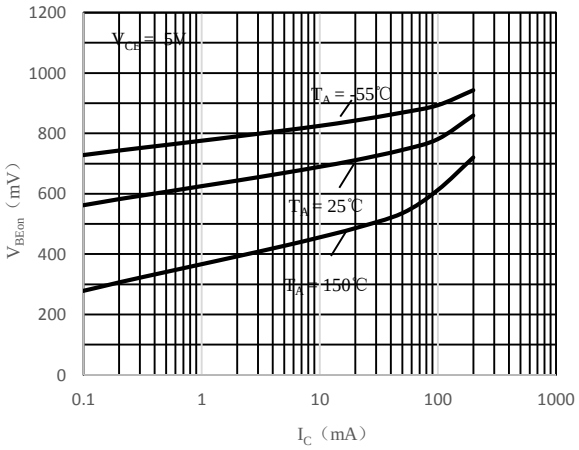


Fig 4 $V_{BE(ON)}$ vs. I_C

Ratings and Characteristic Curves-BC847/848C (@ T_A = 25℃ unless otherwise specified)

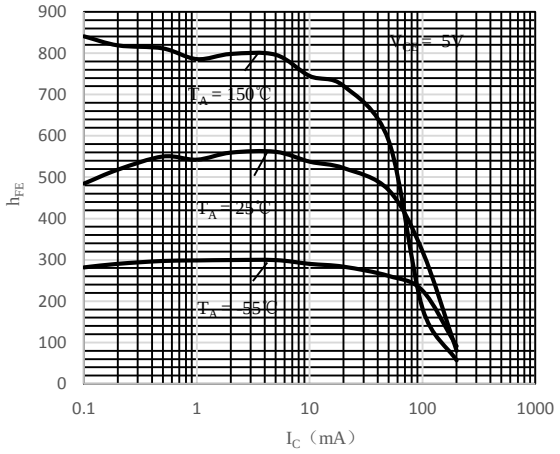


Fig 1 h_{FE} vs. I_C

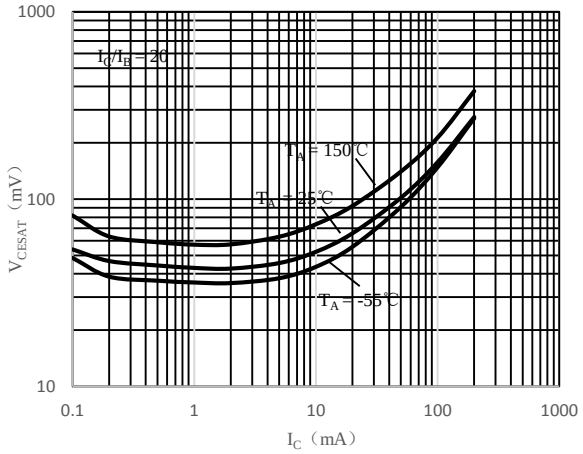


Fig 2 $V_{CE(sat)}$ vs. I_C

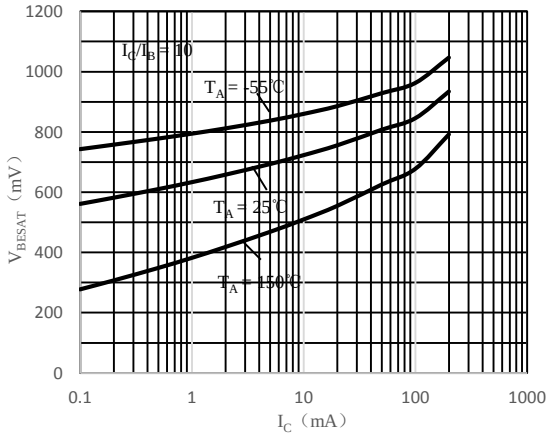


Fig 3 $V_{BE(sat)}$ vs. I_C

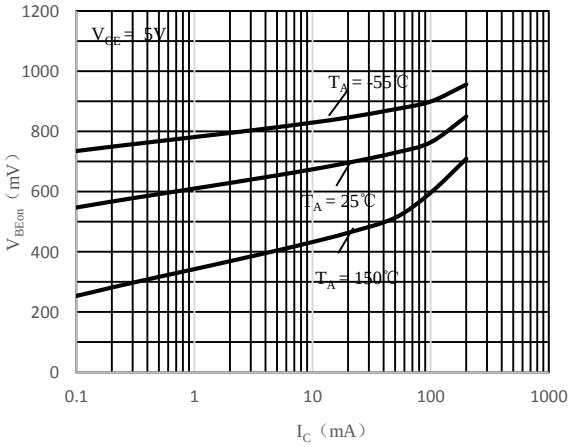
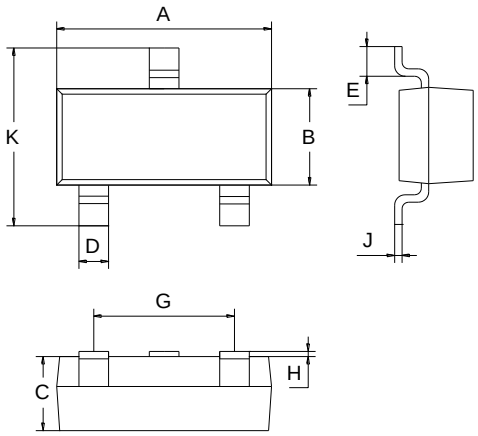


Fig 4 $V_{BE(ON)}$ vs. I_C

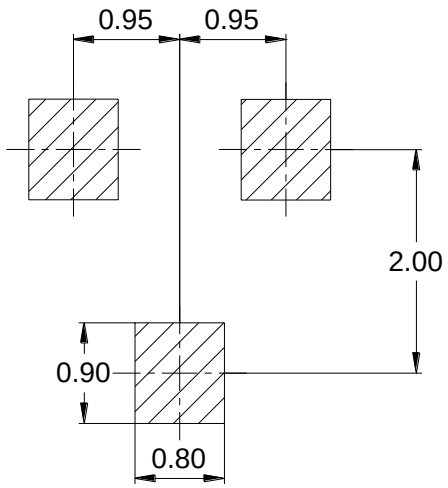
Package Outline Dimensions (Unit: mm)



SOT-23		
Dimension	**Min.**	**Max.**
A	2.70	3.10
B	1.10	1.50
C	0.9	1.1
D	0.3	0.5
E	0.35	0.48
G	1.80	2.00
H	0.02	0.1
J	0.05	0.15
K	2.20	2.60

Package Outline Dimensions (Unit: mm)

SOT-23



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